

PSMN4R1-30YLC

N-channel 30 V 4.35m Ω logic level MOSFET in LFPAK using NextPower technology

12 February 2013

Product data sheet

1. General description

Logic level enhancement mode N-channel MOSFET in LFPAK package. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

2. Features and benefits

- High reliability Power SO8 package, qualified to 175°C
- Low parasitic inductance and resistance
- Optimised for 4.5V Gate drive utilising NextPower Superjunction technology
- Ultra low QG, QGD, & QOSS for high system efficiencies at low and high loads

3. Applications

- DC-to-DC converters
- Load switching
- Power OR-ing
- Server power supplies
- Sync rectifier

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C	-	-	30	V
I _D	drain current	T _{mb} = 25 °C; V _{GS} = 10 V; <u>Fig. 1</u>	-	-	92	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>	-	-	67	W
Tj	junction temperature		-55	-	175	°C
Static characte	eristics					
R _{DSon}	drain-source on-state resistance	V_{GS} = 4.5 V; I_D = 20 A; T_j = 25 °C; Fig. 12	-	4.75	5.7	mΩ
		V_{GS} = 10 V; I_D = 20 A; T_j = 25 °C; Fig. 12	-	3.65	4.35	mΩ
Dynamic chara	acteristics					
Q_{GD}	gate-drain charge	V_{GS} = 4.5 V; I_D = 20 A; V_{DS} = 15 V; Fig. 14; Fig. 15	-	3.5	-	nC



Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Q _{G(tot)}	total gate charge	$V_{GS} = 4.5 \text{ V}; I_D = 20 \text{ A}; V_{DS} = 15 \text{ V};$	-	11	-	nC
		Fig. 14; Fig. 15				

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol		
1	S	source	mb	D I		
2	S	source				
3	S	source	a j		[q]	G A
4	G	gate	<u>g g g g</u>	mbb076 S		
mb	D	mounting base; connected to drain	1 2 3 4 LFPAK; Power- SO8 (SOT669)			

6. Ordering information

Table 3. Ordering information

Type number	Package	ackage				
	Name	Description	Version			
PSMN4R1-30YLC	LFPAK; Power-SO8	plastic single-ended surface-mounted package; 4 leads	SOT669			

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN4R1-30YLC	4C130L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C	-	30	V
V_{DGR}	drain-gate voltage	25 °C ≤ T_j ≤ 175 °C; R_{GS} = 20 kΩ	-	30	V
V_{GS}	gate-source voltage		-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 1</u>	-	92	Α
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 1</u>	-	65	Α

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Symbol	Parameter	Conditions	Min	Max	Unit
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$; Fig. 4	-	367	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>	-	67	W
T _{stg}	storage temperature		-55	175	°C
Tj	junction temperature		-55	175	°C
T _{sld(M)}	peak soldering temperature		-	260	°C
V _{ESD}	electrostatic discharge voltage	MM (JEDEC JESD22-A115)	270	-	V
Source-drai	n diode				
I _S	source current	T _{mb} = 25 °C	-	61	Α
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$	-	367	Α
Avalanche r	ruggedness				
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 92 A; $V_{sup} \le 30$ V; R_{GS} = 50 Ω; unclamped; Fig. 3	-	21	mJ

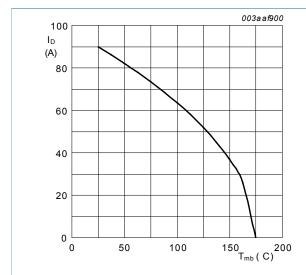


Fig. 1. Continuous drain current as a function of mounting base temperature

$$V_{GS} \ge 10V$$

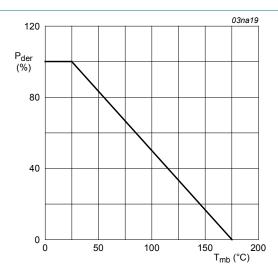


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\%$$

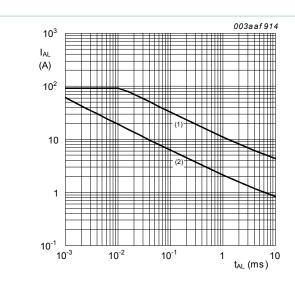
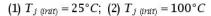


Fig. 3. Single pulse avalanche rating; avalanche current as a function of avalanche time



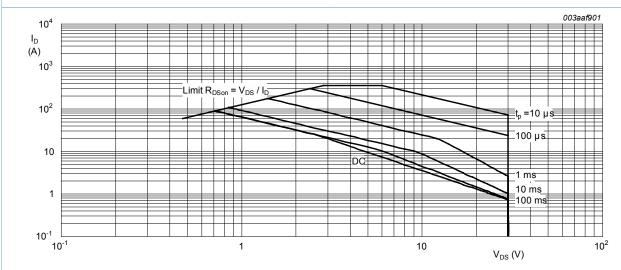


Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

 $T_{mb} = 25$ °C; I_{DM} is a single pulse

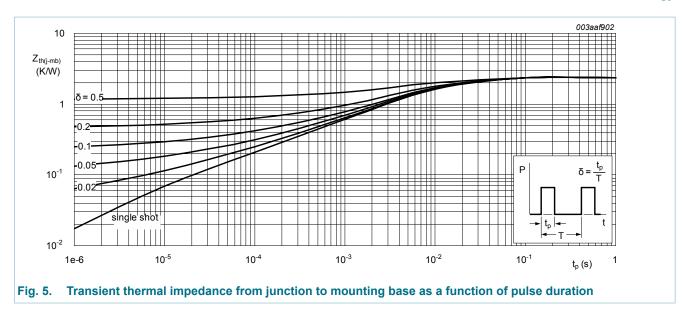
9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5	-	2.05	2.24	K/W

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	30	-	-	V
	breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 °C$	27	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C};$ Fig. 10; Fig. 11	1.05	1.58	1.95	V
		I_D = 10 mA; V_{DS} = V_{GS} ; T_j = 150 °C	0.5	-	-	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C}$	-	-	2.25	V
I _{DSS} drain leakage current	drain leakage current	$V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	1	μΑ
	V _{DS} = 30 V; V _{GS} = 0 V; T _j = 150 °C	-	-	100	μΑ	
I _{GSS} gate leakage current	gate leakage current	V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
		V _{GS} = -16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state resistance	V_{GS} = 4.5 V; I_D = 20 A; T_j = 25 °C; Fig. 12	-	4.75	5.7	mΩ
		V _{GS} = 4.5 V; I _D = 20 A; T _j = 150 °C; Fig. 12; Fig. 13	-	-	9.4	mΩ
		V_{GS} = 10 V; I_D = 20 A; T_j = 25 °C; Fig. 12	-	3.65	4.35	mΩ
		V _{GS} = 10 V; I _D = 20 A; T _j = 150 °C; Fig. 12; Fig. 13	-	-	7.25	mΩ
R_G	gate resistance	f = 1 MHz	-	1.9	3.8	Ω

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Dynamic ch	naracteristics					
Q _{G(tot)} tot	total gate charge	I _D = 20 A; V _{DS} = 15 V; V _{GS} = 10 V; Fig. 14; Fig. 15	-	23	-	nC
		I _D = 20 A; V _{DS} = 15 V; V _{GS} = 4.5 V; Fig. 14; Fig. 15	-	11	-	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V	-	20	-	nC
Q_{GS}	gate-source charge	I _D = 20 A; V _{DS} = 15 V; V _{GS} = 4.5 V;	-	3.5	-	nC
Q _{GS(th)}	pre-threshold gate- source charge	Fig. 14; Fig. 15	-	2.3	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge		-	1.2	-	nC
Q_{GD}	gate-drain charge		-	3.5	-	nC
V _{GS(pl)}	gate-source plateau voltage	I _D = 20 A; V _{DS} = 15 V; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	2.66	-	V
C _{iss}	input capacitance	$V_{DS} = 15 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ °C}; Fig. 16$	-	1502	-	pF
C _{oss}	output capacitance		-	316	-	pF
C _{rss}	reverse transfer capacitance		-	106	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 15 V; R_L = 0.6 Ω ; V_{GS} = 4.5 V;	-	16	-	ns
t _r	rise time	$R_{G(ext)} = 4.7 \Omega$	-	19	-	ns
$t_{d(off)}$	turn-off delay time		-	24	-	ns
t _f	fall time		-	10	-	ns
Q _{oss}	output charge	$V_{GS} = 0 \text{ V}; V_{DS} = 15 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ °C}$	-	8	-	nC
Source-dra	in diode					
V _{SD}	source-drain voltage	$I_S = 20 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}; Fig. 17$	-	0.8	1.1	V
t _{rr}	reverse recovery time	$I_S = 20 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$	-	23	-	ns
Q _r	recovered charge	V _{DS} = 15 V	-	15	-	nC
ta	reverse recovery rise time	$V_{GS} = 0 \text{ V}; I_S = 20 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s};$ $V_{DS} = 15 \text{ V}; Fig. 18$	-	13.5	-	ns
t _b	reverse recovery fall time		-	9.5	-	ns

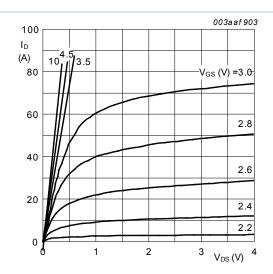


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values



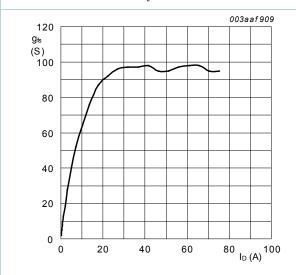


Fig. 8. Forward transconductance as a function of drain current; typical values

$$T_j = 25^{\circ}C; \ V_{DS} = 10V$$

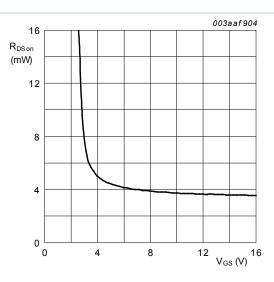


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$$T_j = 25^{\circ}C; \ I_D = 20A$$

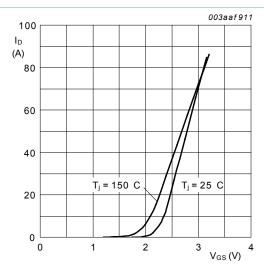


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$$V_{DS} = 10V$$

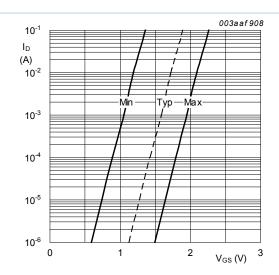


Fig. 10. Sub-threshold drain current as a function of gate-source voltage

$$T_j = 25^{\circ}C; \ V_{DS} = 5V$$

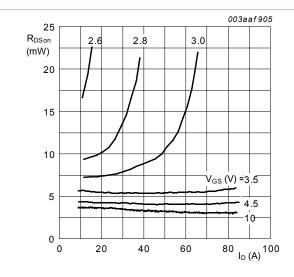


Fig. 12. Drain-source on-state resistance as a function of drain current; typical values

$$T_i = 25^{\circ}C$$

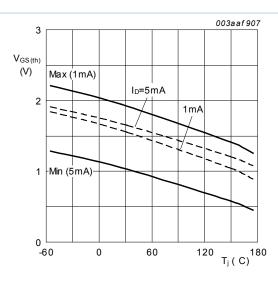


Fig. 11. Gate-source threshold voltage as a function of junction temperature

$$V_{\it DS} = V_{\it GS}$$

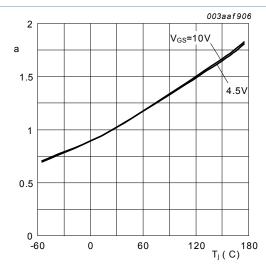


Fig. 13. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon(25^{\circ}C)}}$$

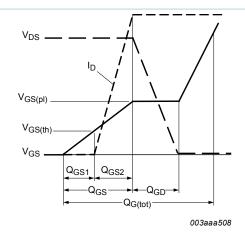


Fig. 14. Gate charge waveform definitions

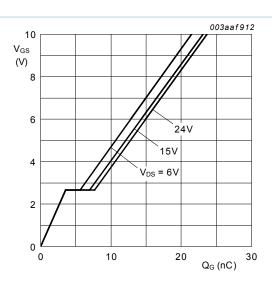


Fig. 15. Gate-source voltage as a function of gate charge; typical values

$$T_i = 25^{\circ}C; I_D = 20A$$

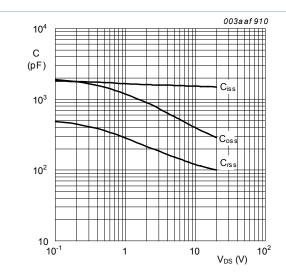


Fig. 16. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$$V_{GS} = 0V; f = 1MHz$$

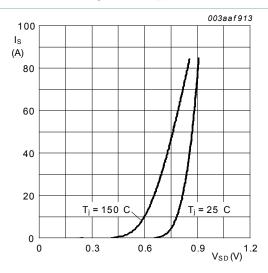
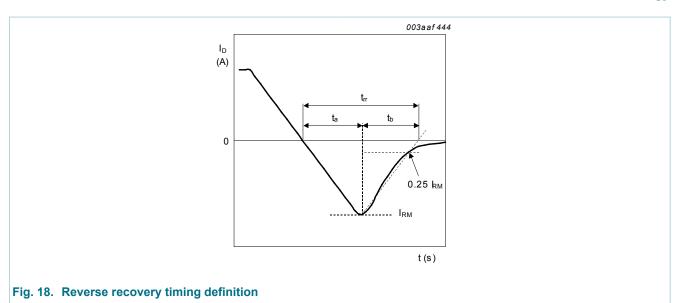


Fig. 17. Source current as a function of source-drain voltage; typical values

$$V_{GS} = 0V$$



Product data sheet

11. Package outline

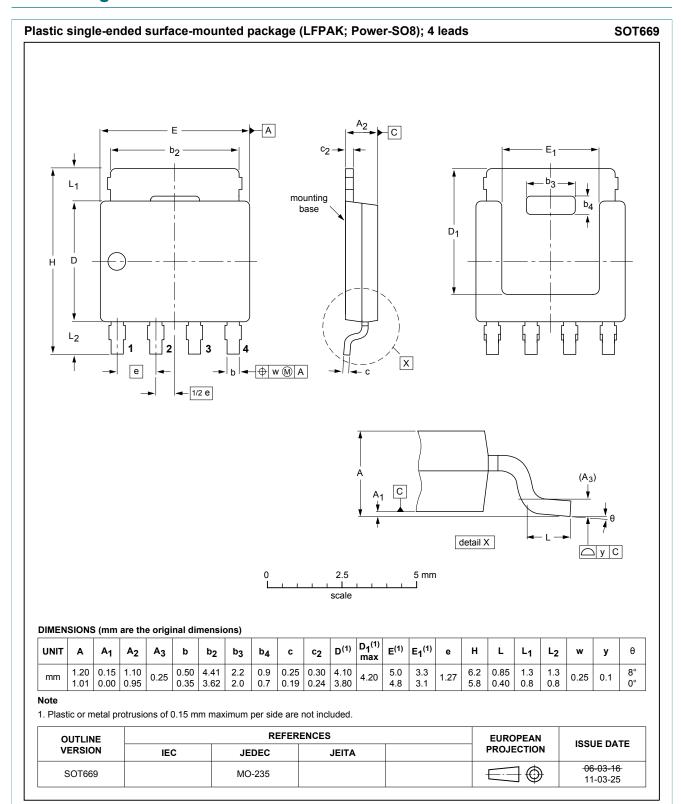


Fig. 19. Package outline LFPAK; Power-SO8 (SOT669)

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